

# Silicon Detectors

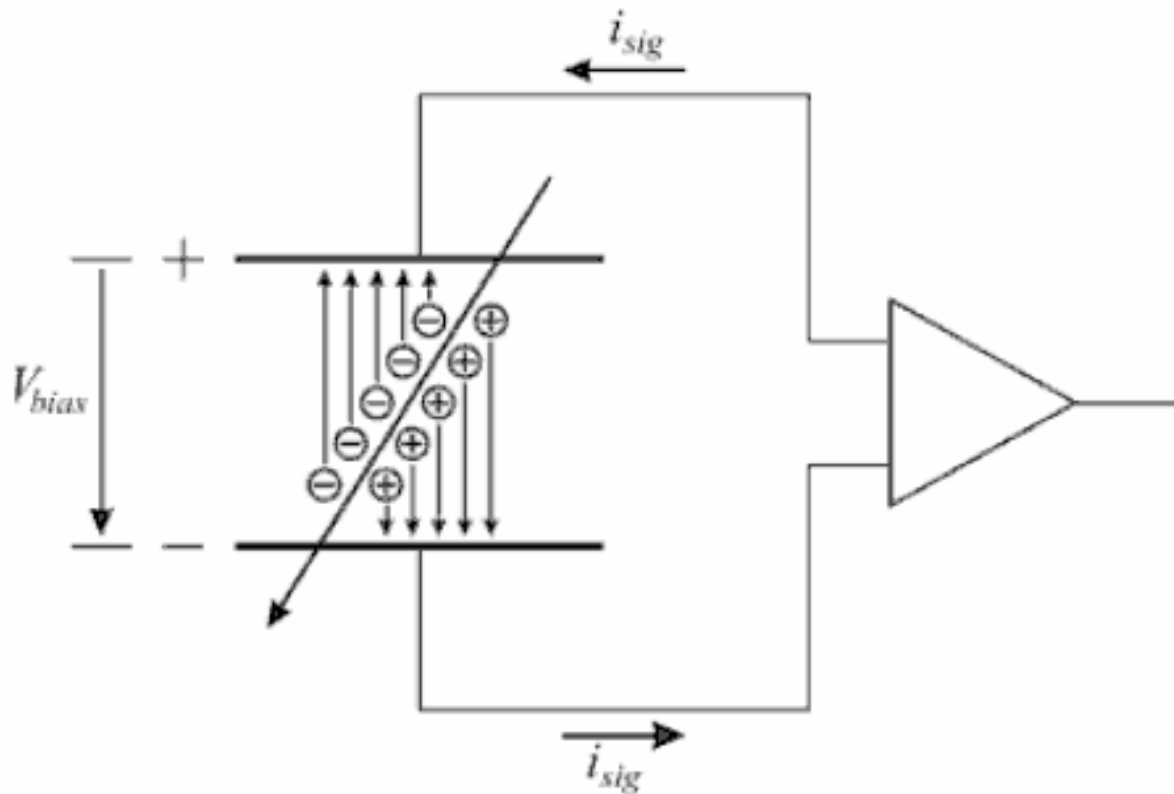
Caio Laganá

SPRACE - IFT/UNESP

# Basic principle of detectors



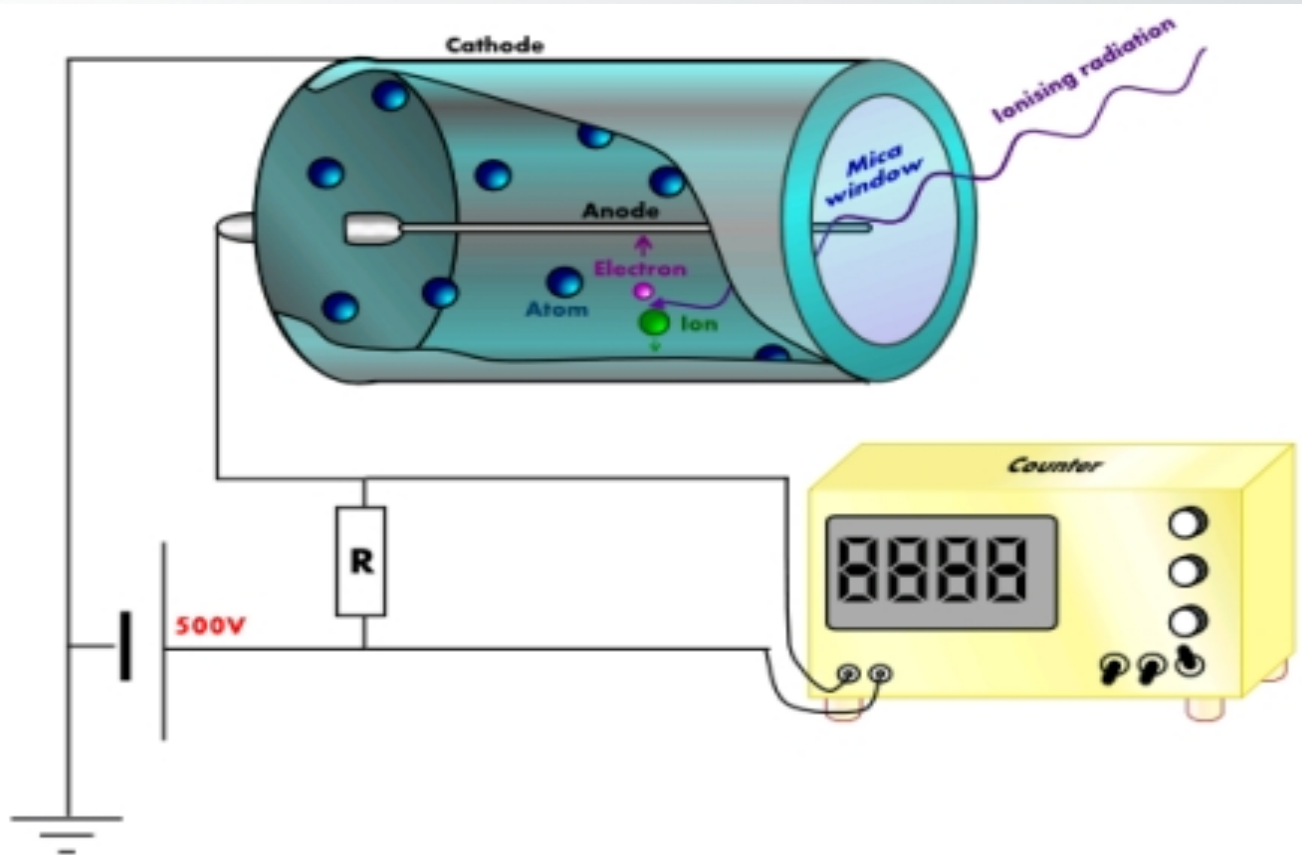
- Radiation produces free charges when passing through matter
- Free charges are collected, generating a signal



# Basic principle of detectors



- e.g. Geiger Counter



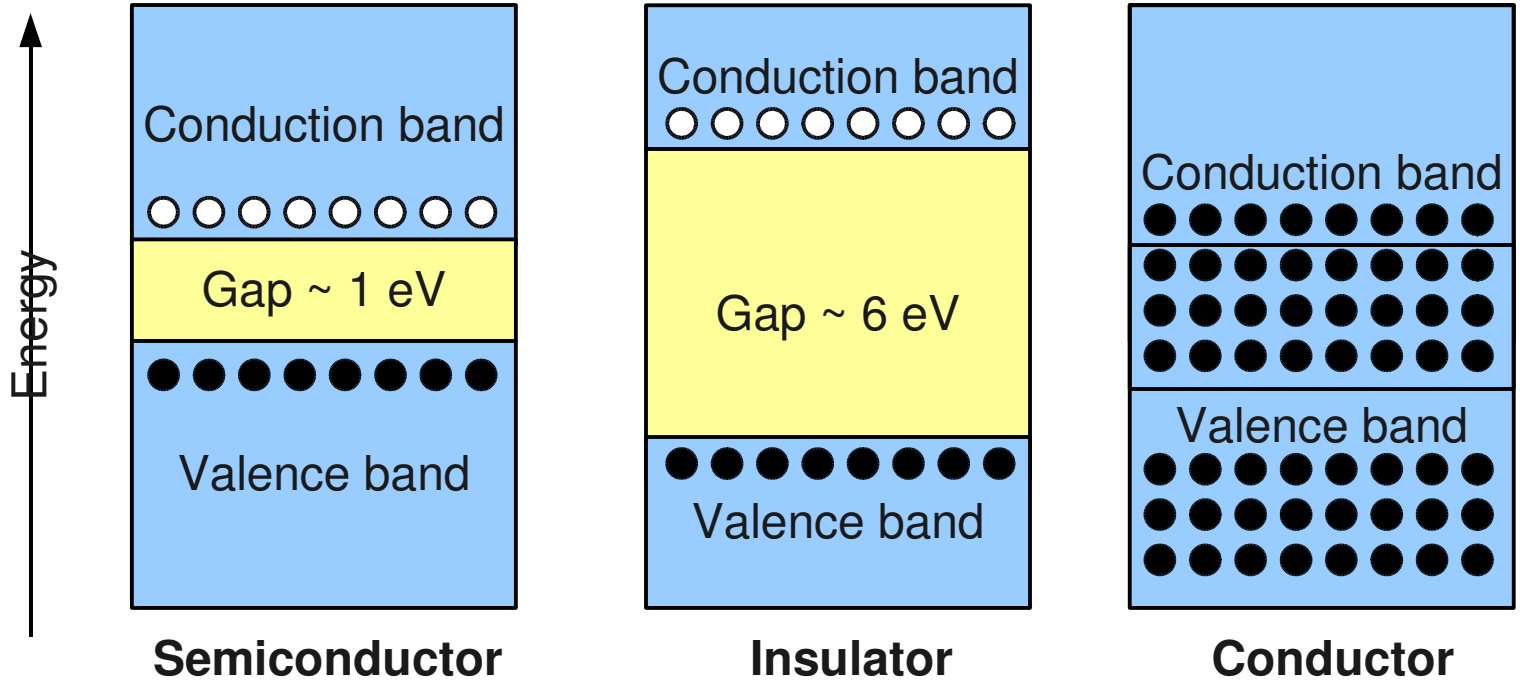
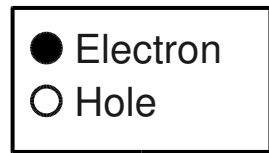
- In silicon detectors, the 'ionizing chamber' is a p-n junction



# Band structure



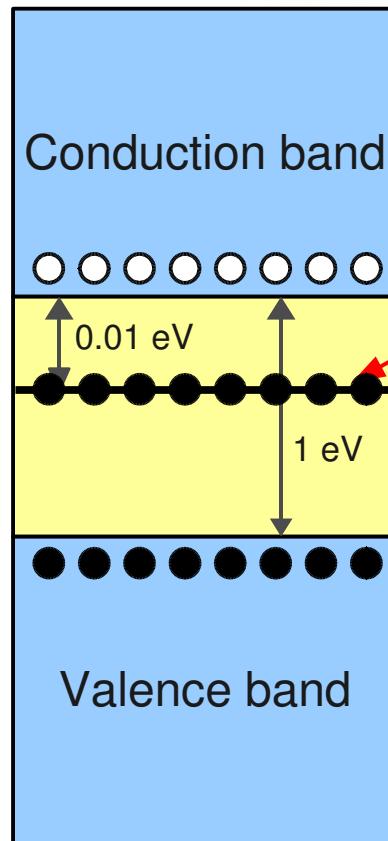
- Periodical boundary conditions in Schroedinger equation gives rise to the band structure
- The width of the gap is determined by the lattice spacing between the atoms



# Doped semiconductors



- Dopping the silicon ( $Z=14$ ) with phosphorous ( $Z=15$ ) creates a new energy level close to the conduction band



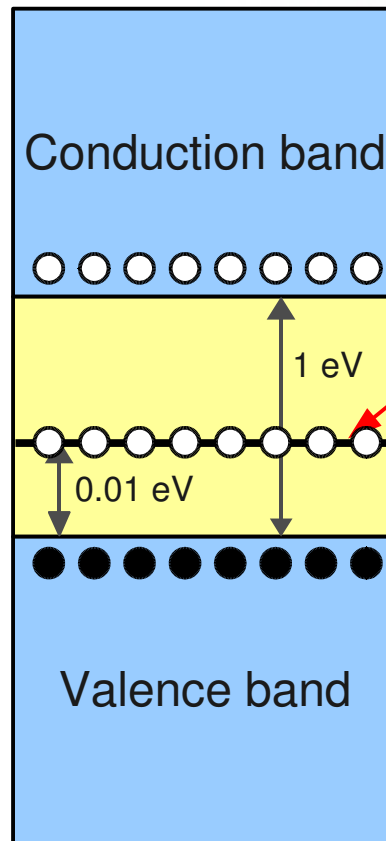
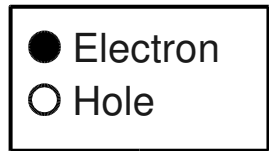
Energy level created by n-dopant (extra electron)

n-type

# Doped semiconductors



- Dopping the silicon ( $Z=14$ ) with gallium ( $Z=31$ ) creates a new, empty energy level close to the valence band



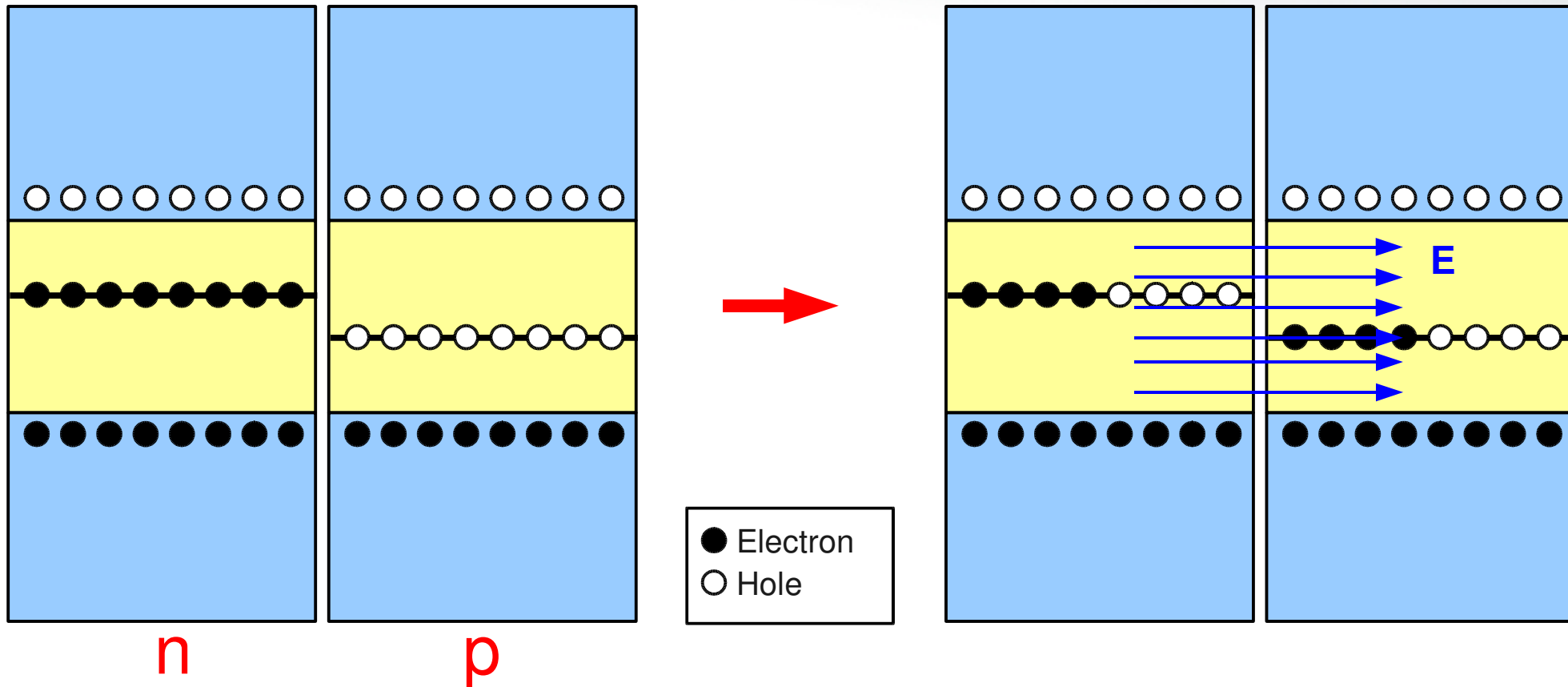
(empty) energy level  
created by p-dopant  
(extra hole)

p-type

# The p-n junction



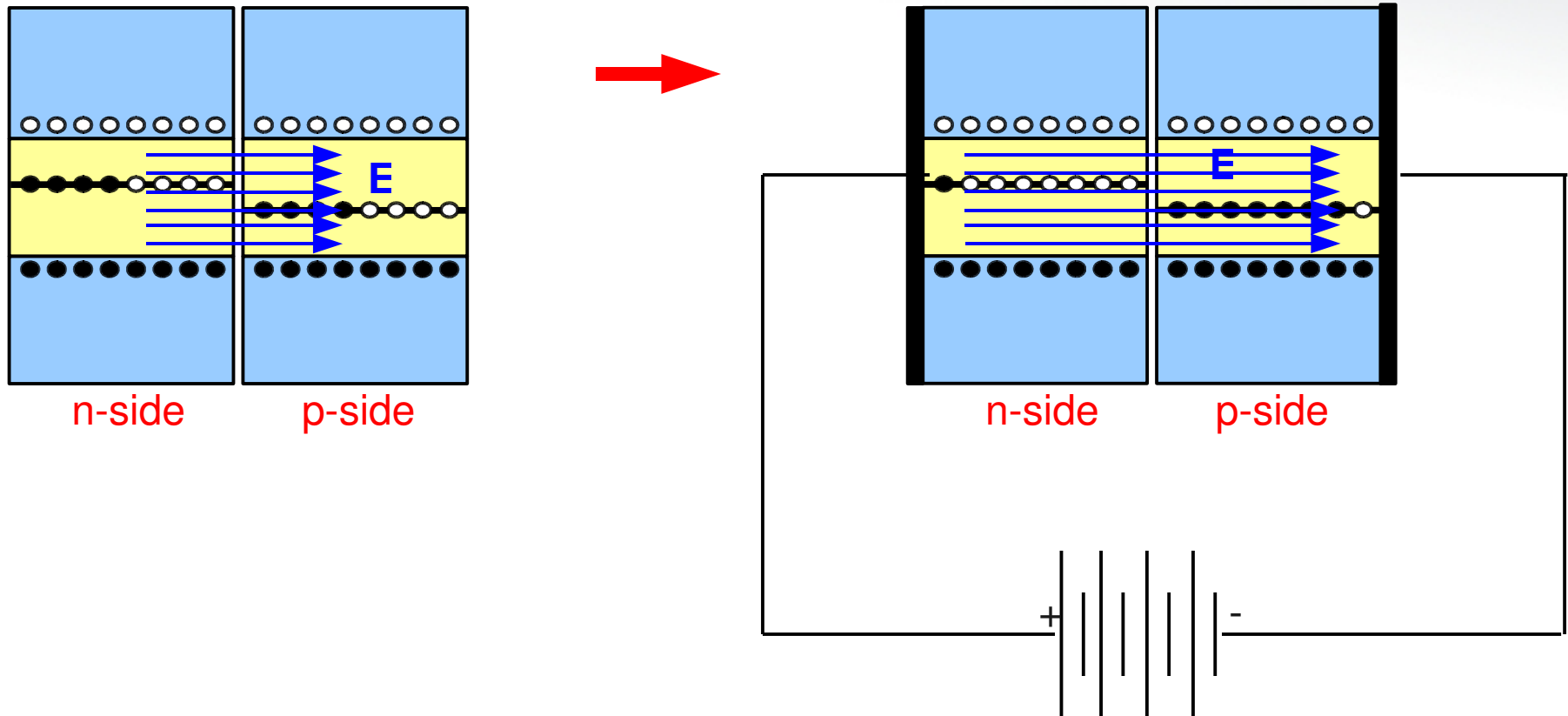
- Putting them together, the diffusion of electrons turns the (initially neutral) n-material positive, and the p-material negative, creating an electric field between them



# The p-n junction



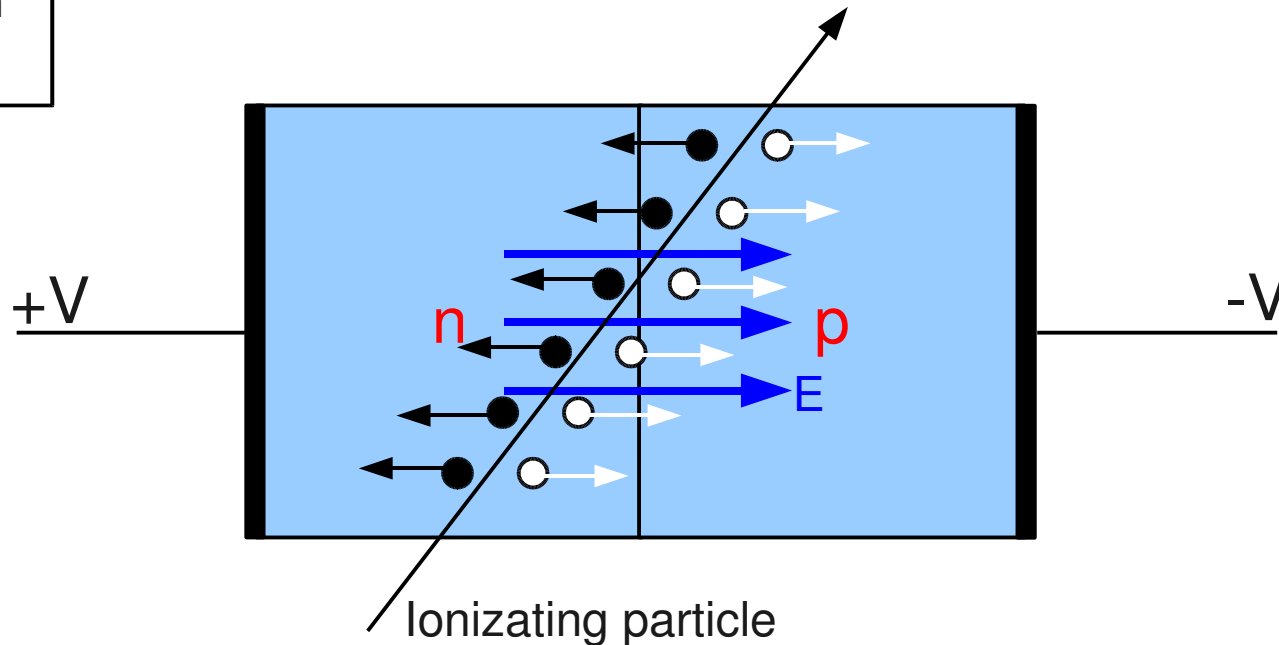
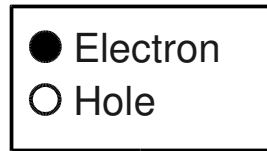
- Under reverse bias (+V on n-side, -V on p-side) the electric field region increases







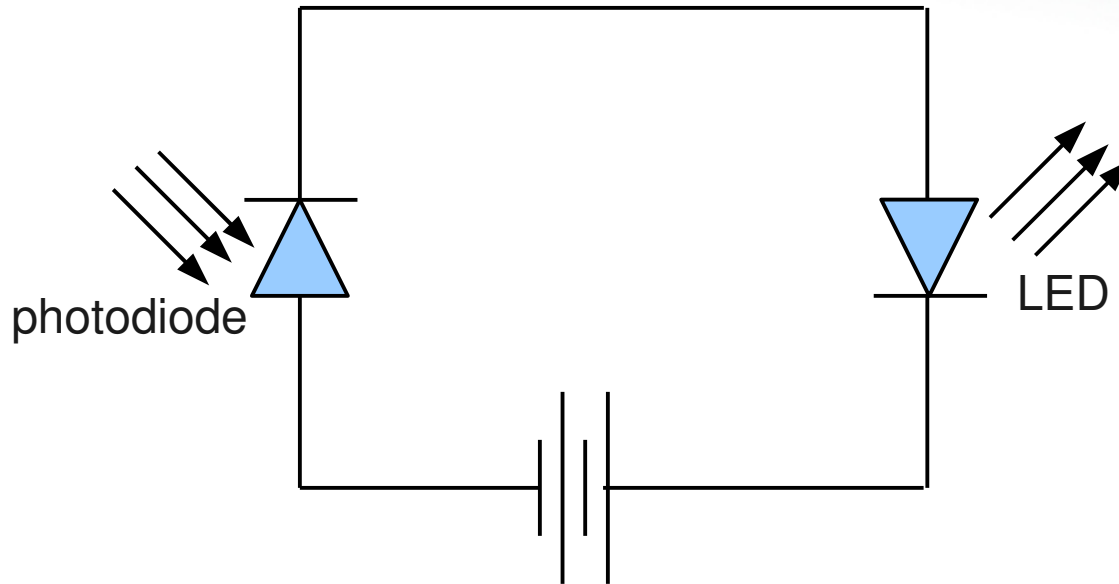
- When a particle passes through the sensitive region, it ionizes the medium, liberating charges which are collected by the electric field
- In silicon, the minimum energy for electron-hole creation is 3.62 eV



# *Practical example*



- Photodiode as an example of a p-n junction





# Silicon detectors in the CMS



- p-n junctions can be arranged in several ways to make a detector
- The CMS has a *pixel* and *microstrips* system, which compose the *tracker*

## CMS Detector

Pixels  
Tracker  
ECAL  
HCAL  
Solenoid  
Steel Yoke  
Muons

**STEEL RETURN YOKE**  
~13000 tonnes

**SUPERCONDUCTING SOLENOID**  
Niobium-titanium coil carrying ~18000 A

**HADRON CALORIMETER (HCAL)**  
Brass + plastic scintillator  
~7k channels

Total weight : 14000 tonnes  
Overall diameter : 15.0 m  
Overall length : 28.7 m  
Magnetic field : 3.8 T

### SILICON TRACKER

Pixels ( $100 \times 150 \mu\text{m}^2$ )  
~1m<sup>2</sup> ~66M channels  
Microstrips ( $80\text{-}180\mu\text{m}$ )  
~200m<sup>2</sup> ~9.6M channels

### CRYSTAL ELECTROMAGNETIC CALORIMETER (ECAL)

~76k scintillating PbWO<sub>3</sub> crystals

### PRESHOWER

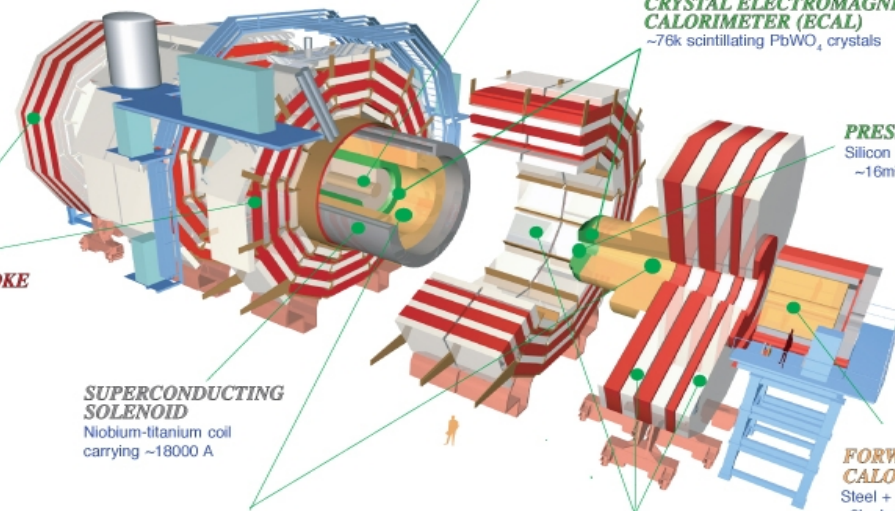
Silicon strips  
~16m<sup>2</sup> ~137k channels

### FORWARD CALORIMETER

Steel + quartz fibres  
~2k channels

### MUON CHAMBERS

Barrel: 250 Drift Tube & 480 Resistive Plate Chambers  
Endcaps: 468 Cathode Strip & 432 Resistive Plate Chambers



# CMS Detector

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Tracker  
ECAL  
HCAL  
Solenoid  
Steel Yoke  
Muons

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~1m<sup>2</sup> ~66M channels  
Microstrips (80-180 $\mu\text{m}$ )  
~200m<sup>2</sup> ~9.6M channels

**CRYSTAL ELECTROMAGNETIC CALORIMETER (ECAL)**  
~76k scintillating PbWO<sub>4</sub> crystals

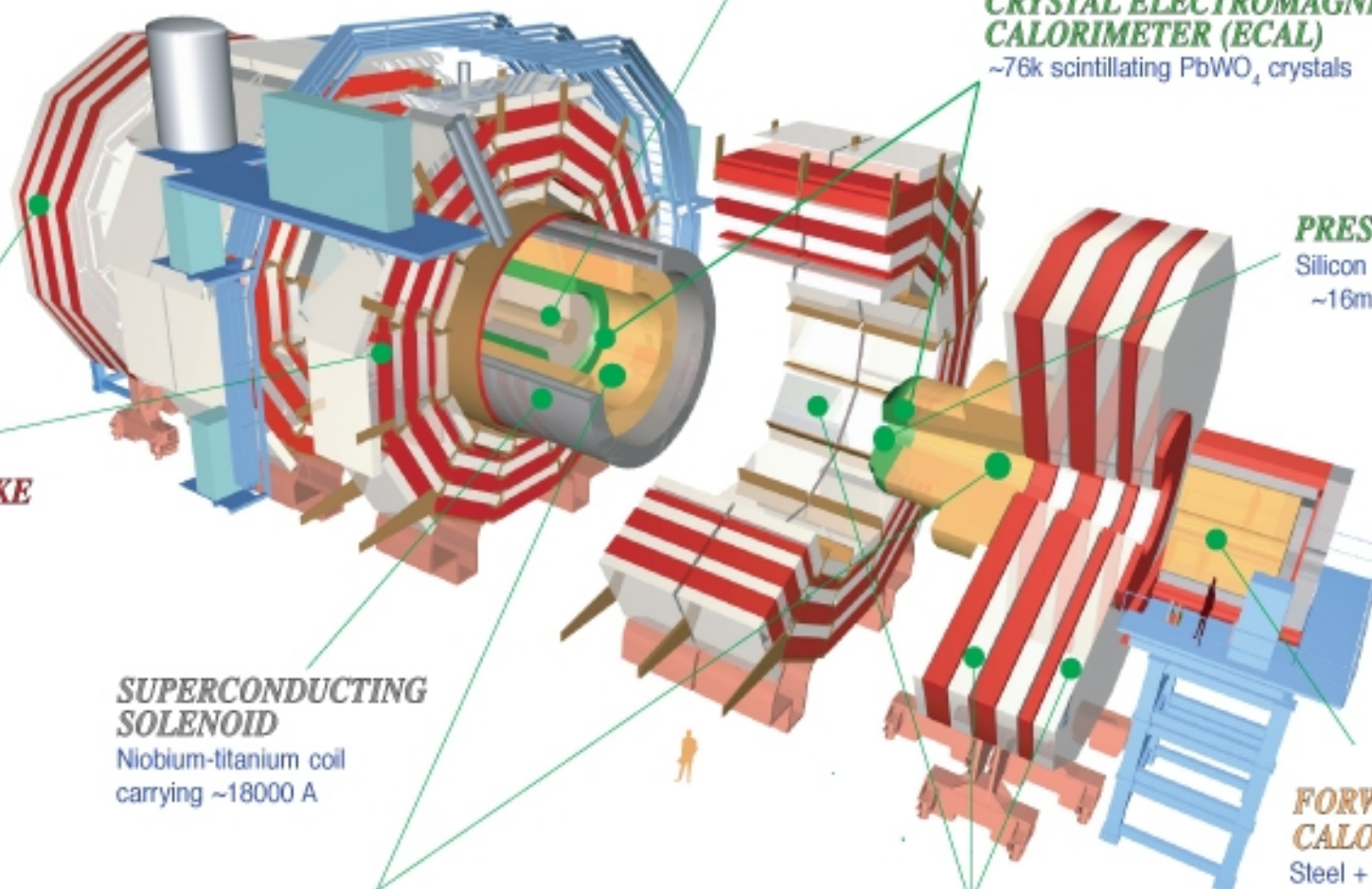
**PRESHOWER**  
Silicon strips  
~16m<sup>2</sup> ~137k channels

**FORWARD CALORIMETER**  
Steel + quartz fibres  
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Barrel: 250 Drift Tube & 480 Resistive Plate Chambers  
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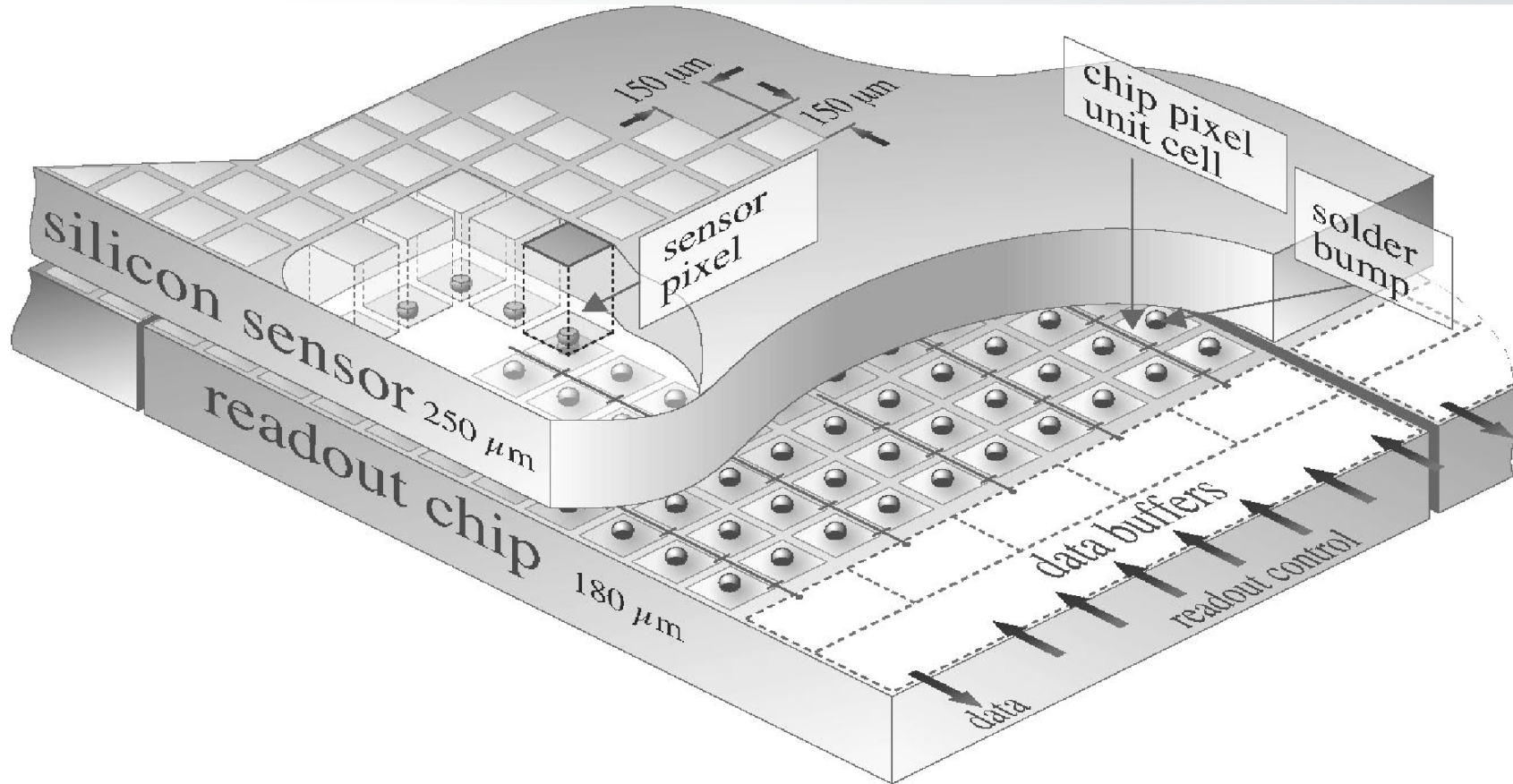




# The pixel system

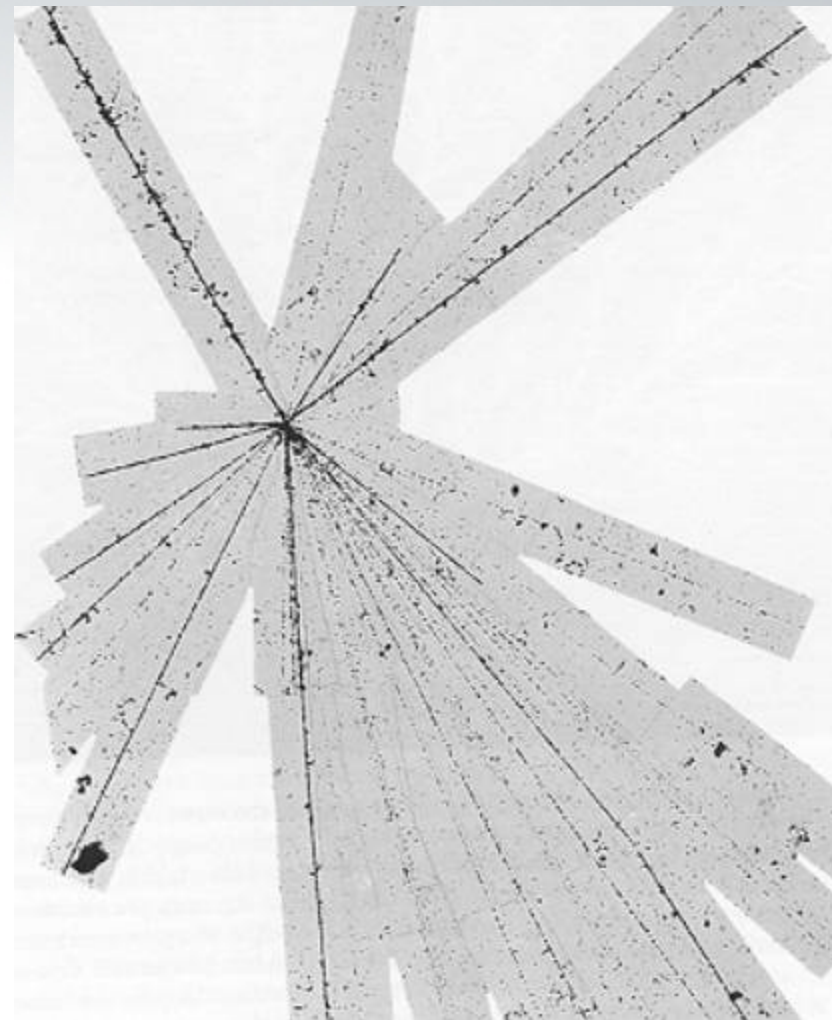
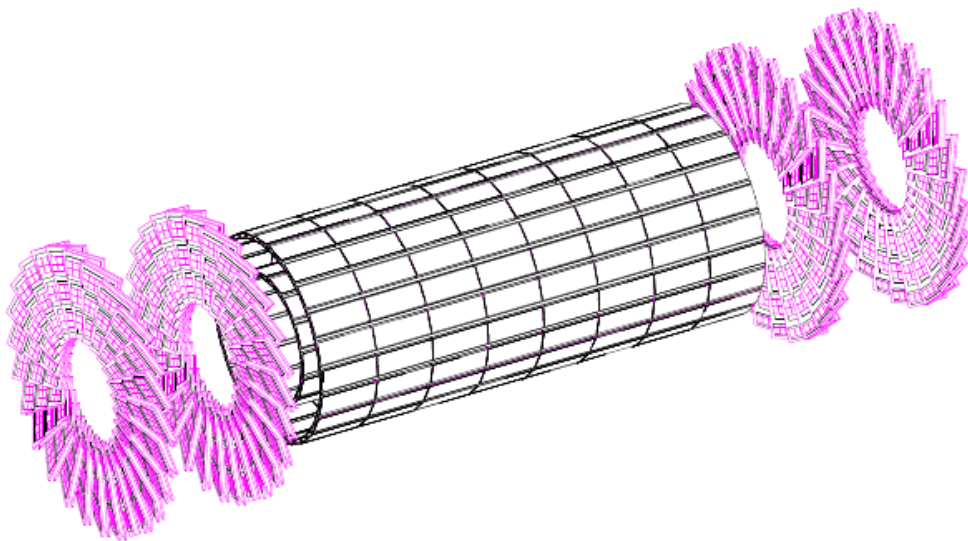


- Each pixel is a p-n junction





- The pixel system has a track accuracy of 2 micro, almost the 1 micro resolution of photographic emulsion

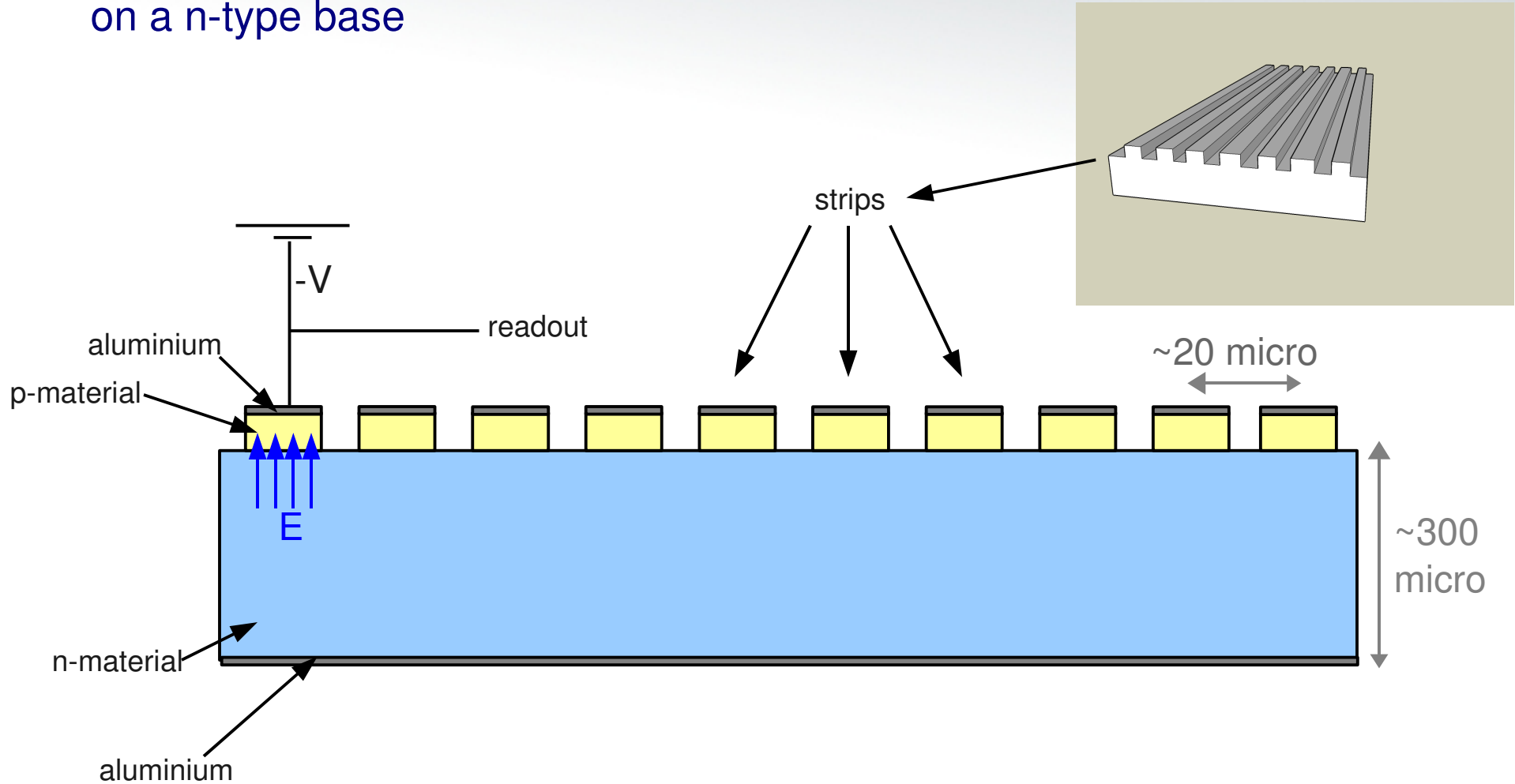


**Fig. 2.3:** Perspective view of the CMS pixel system in the high-luminosity configuration.

# The Micro Strip System



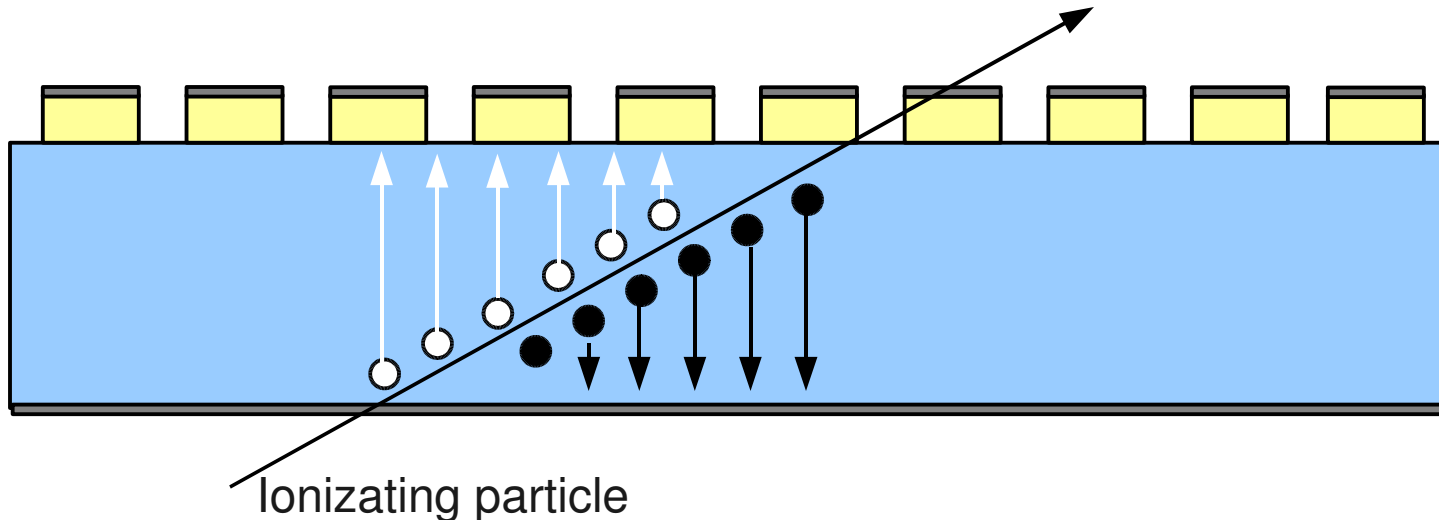
- The micro strips system consist of p-type strips on a n-type base



# The Micro Strip System



- The micro strips system is less accurate than pixels and subjected to more noise, because each strip may receive several hits; that's because pixels are closer to the beam than strips

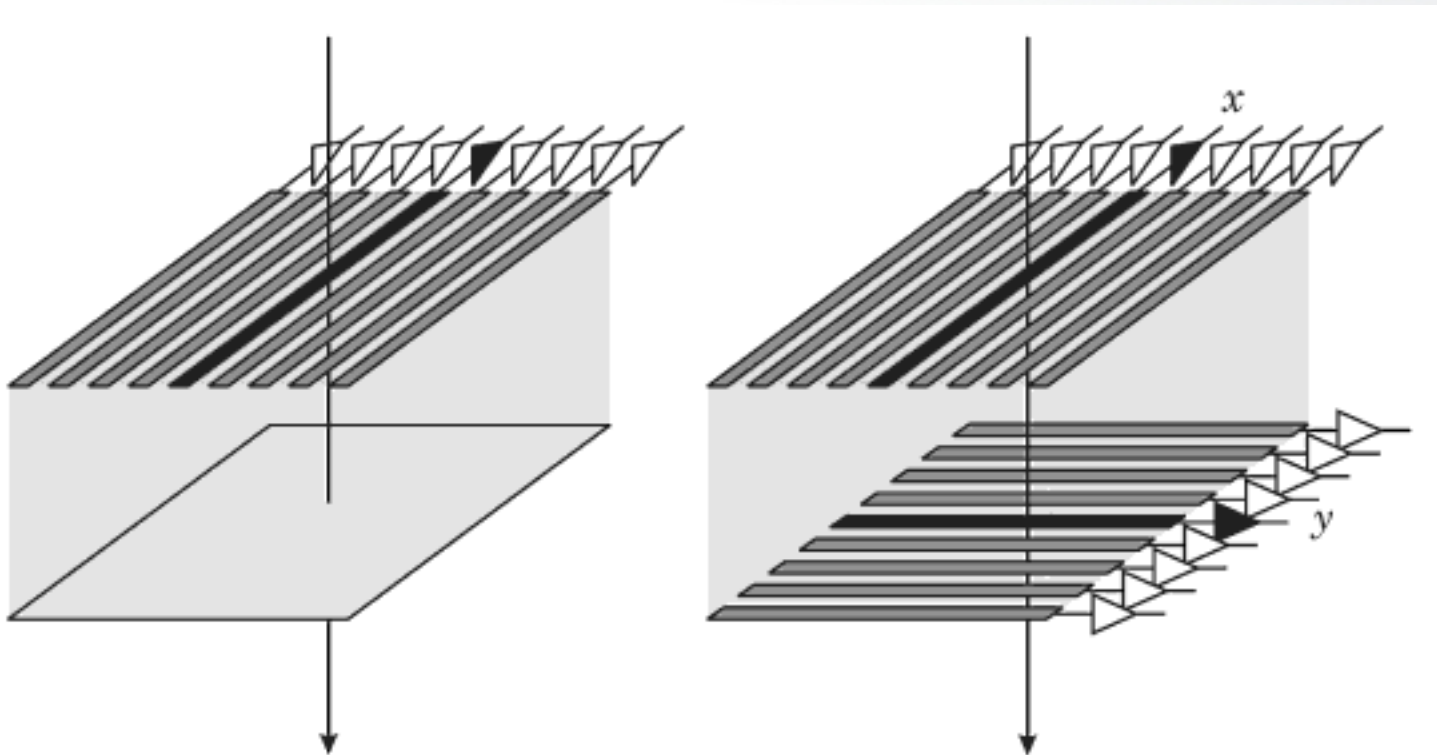




# Micro Strips



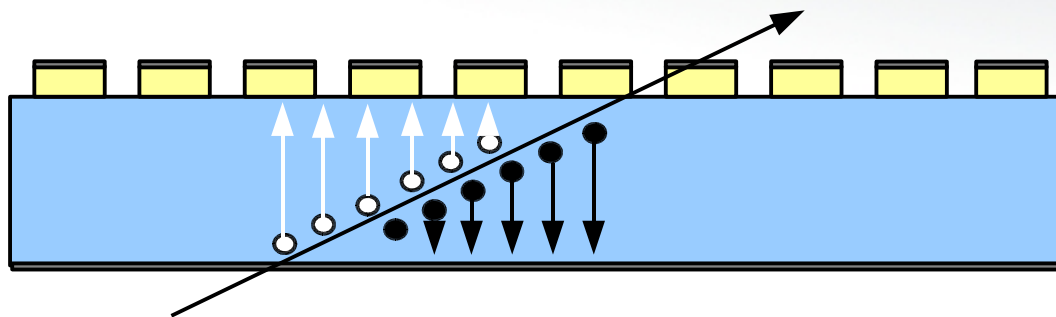
- Micro strips can be arranged in a way to give (x,y) position



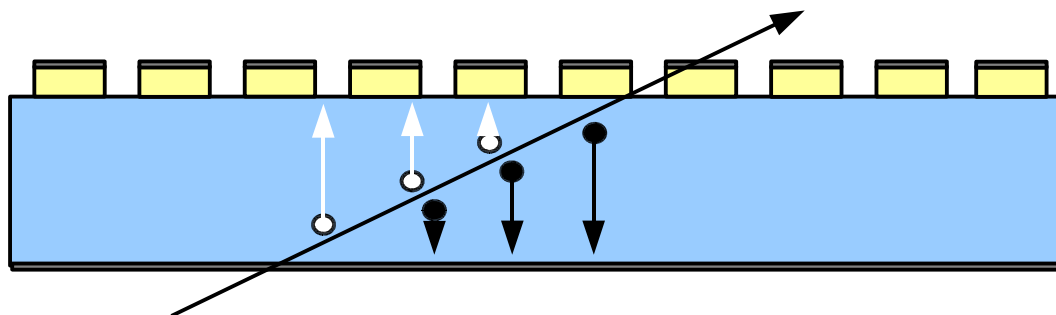
# $dE/dx$ measurement



- $dE/dx$  information is proportional to the number of ionized atoms



High  $dE/dx$



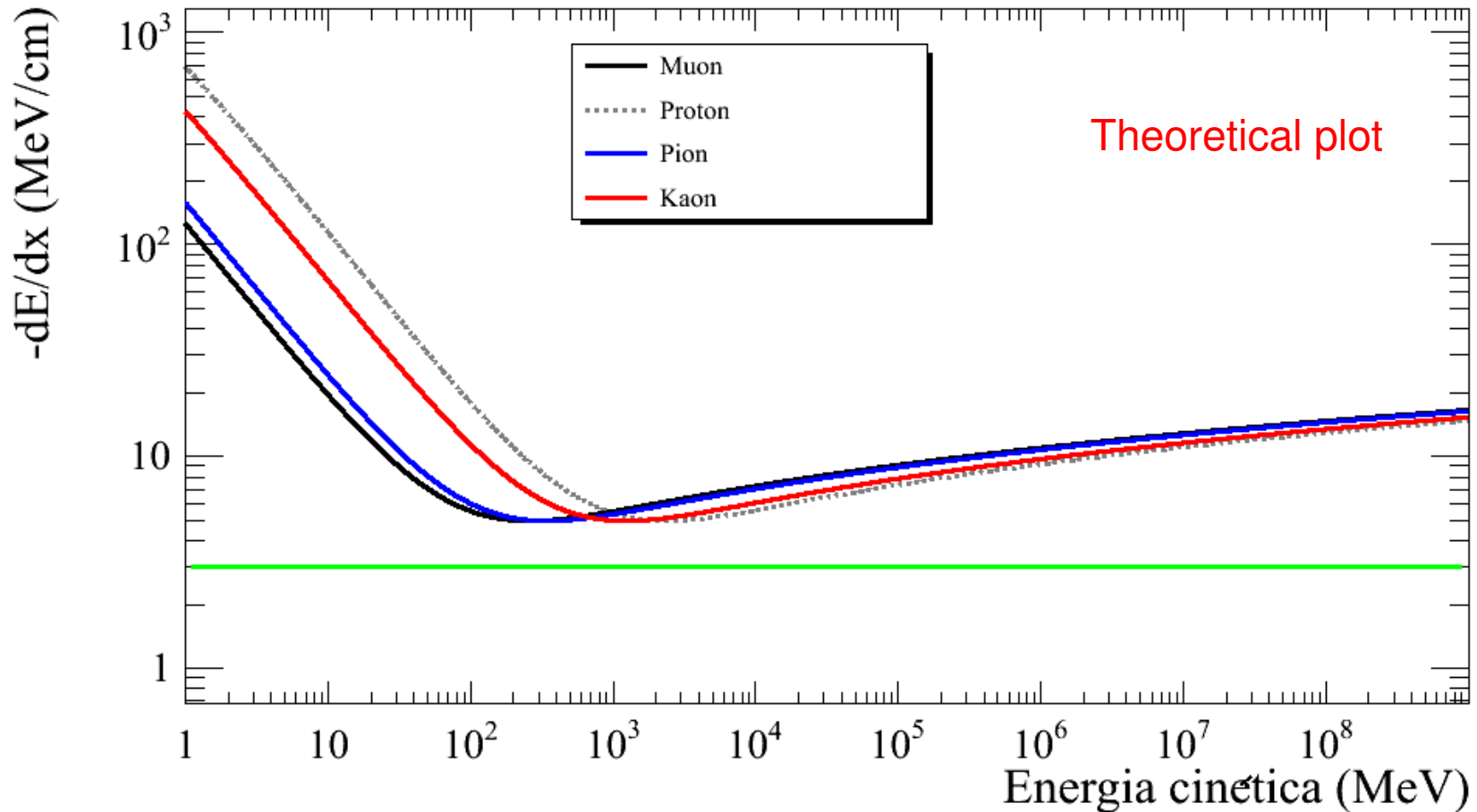
Low  $dE/dx$



# $dE/dx$ analysis



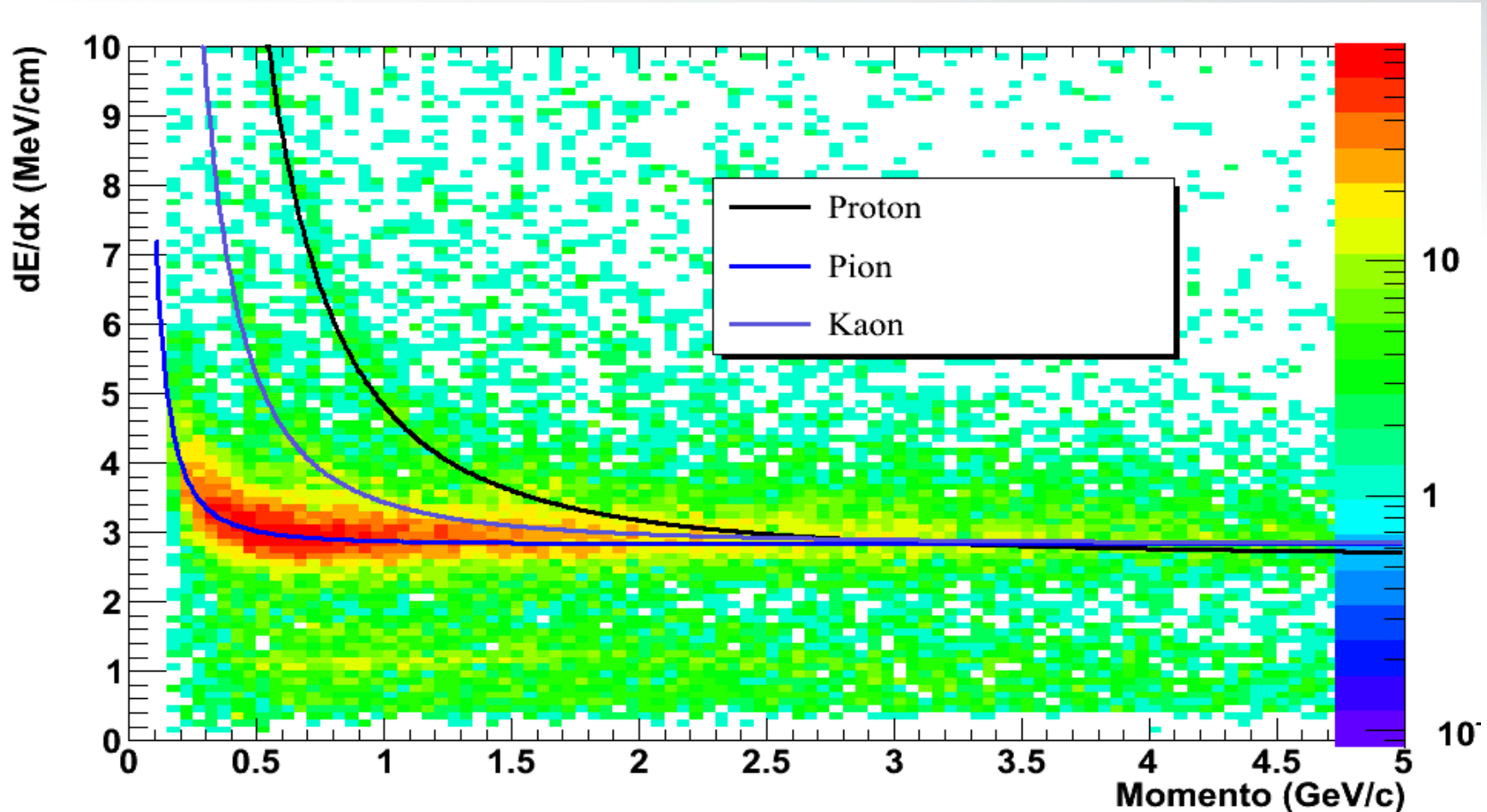
- $dE/dx$  depends on the mass of each particle



# $dE/dx$ analysis



- Using  $dE/dx$  information it is possible to identify the particle

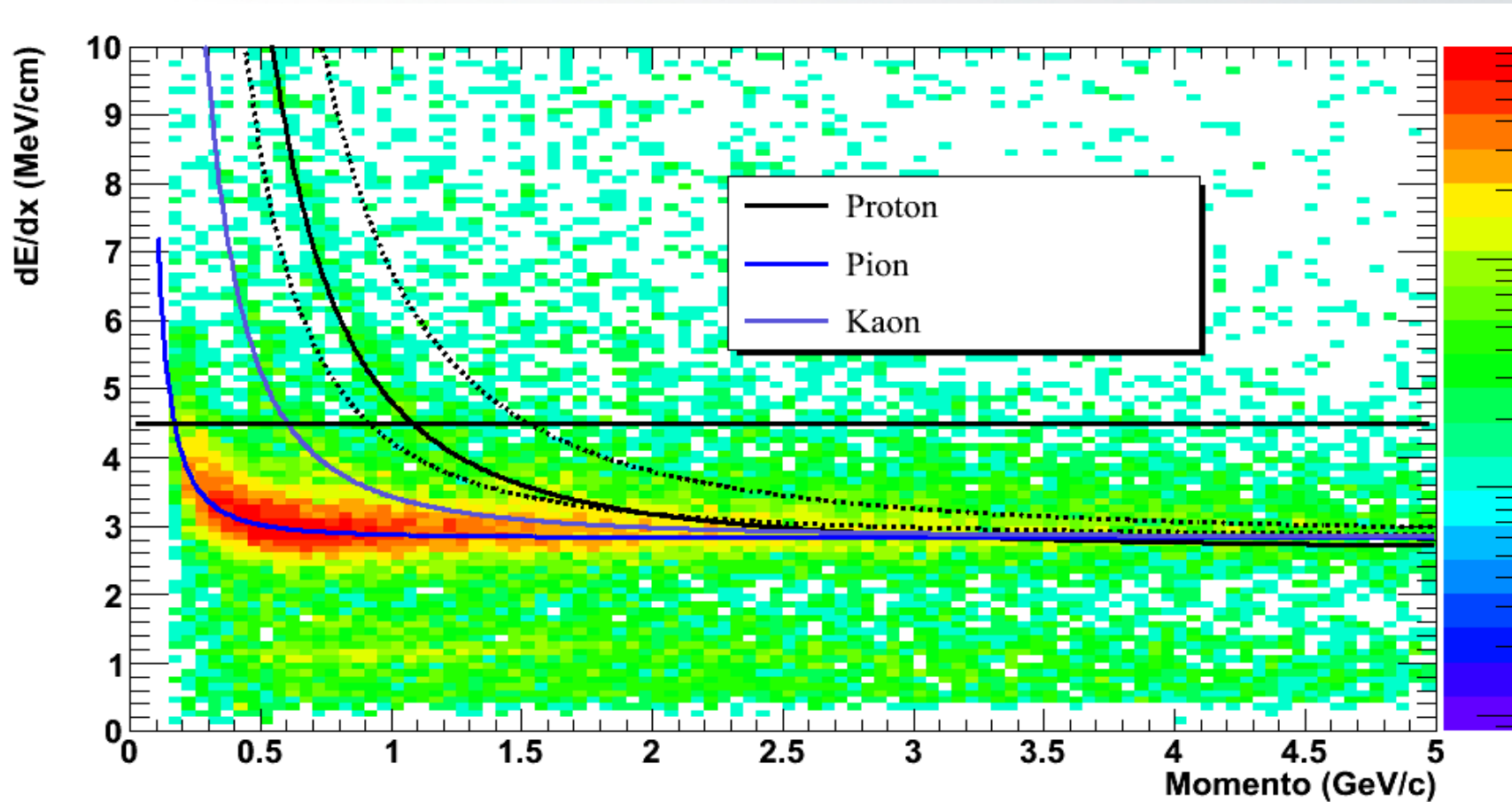


900 GeV data plot

# $dE/dx$ analysis



- One can select particles defining a region in the ( $dE/dx$ ,  $P$ ) plane

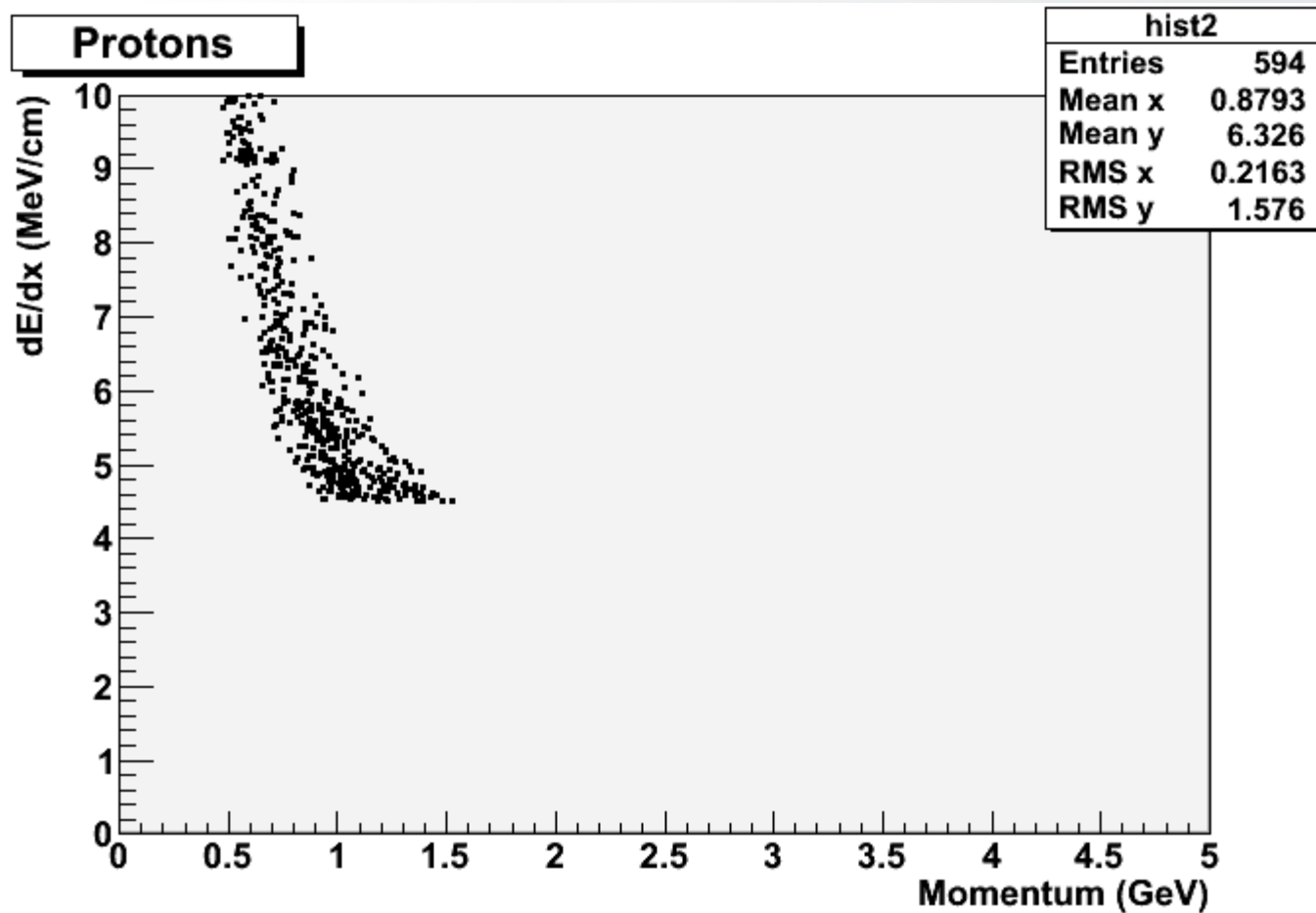




# *$dE/dx$ analysis*



- Example of protons selection

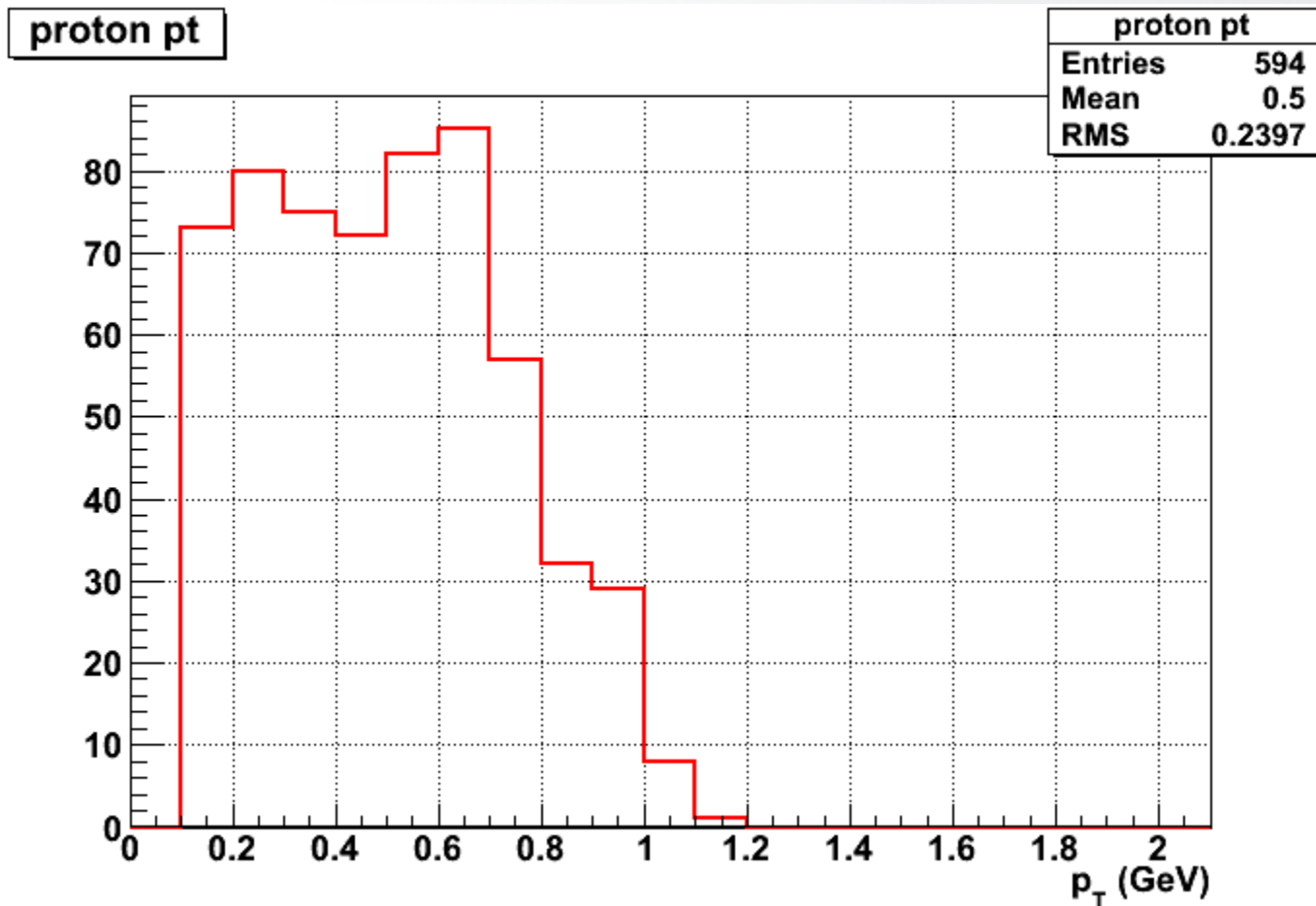




# $dE/dx$ analysis



- Once selected, one are able to extract informations from the particle, e.g. the  $p_T$  distribution of the protons





# *References*



- [1] H. Spieler, Semiconductor detector systems
- [2] W. R. Leo, Techniques for Nuclear and Particle Physics Experiments
- [3] PDG
- [4] [http://cmsdoc.cern.ch/cms/TDR/TRACKER/tracker\\_tdr\\_files.html](http://cmsdoc.cern.ch/cms/TDR/TRACKER/tracker_tdr_files.html)